

# Development of Ultra-Fast Silicon Detectors for 4D Tracking

N. Cartiglia<sup>1</sup>, G. F. Dalla Betta<sup>2</sup>, F. Ficorella<sup>3</sup>, M. Boscardin<sup>3</sup>, G. Paternoster<sup>3</sup>,  
L. Pancheri<sup>2</sup>, F. Cenna<sup>1,4</sup>, M. Ferrero<sup>1</sup>, V. Sola<sup>1,4</sup>, R. Arcidiacono<sup>1,5</sup>,  
M. Obertino<sup>1,4</sup>, V. Monaco<sup>1,4</sup>, R. Bellan<sup>1,4</sup>, A. Staiano<sup>1</sup>, S. Durando<sup>1,4</sup>

<sup>1</sup>Istituto Nazionale di Fisica Nucleare, Torino, Italy

<sup>2</sup>Universita' di Trento, Trento, Italy

<sup>3</sup>Fondazione Bruno Kessler, Trento, Italy

<sup>4</sup>Universita' di Torino, Torino, Italy

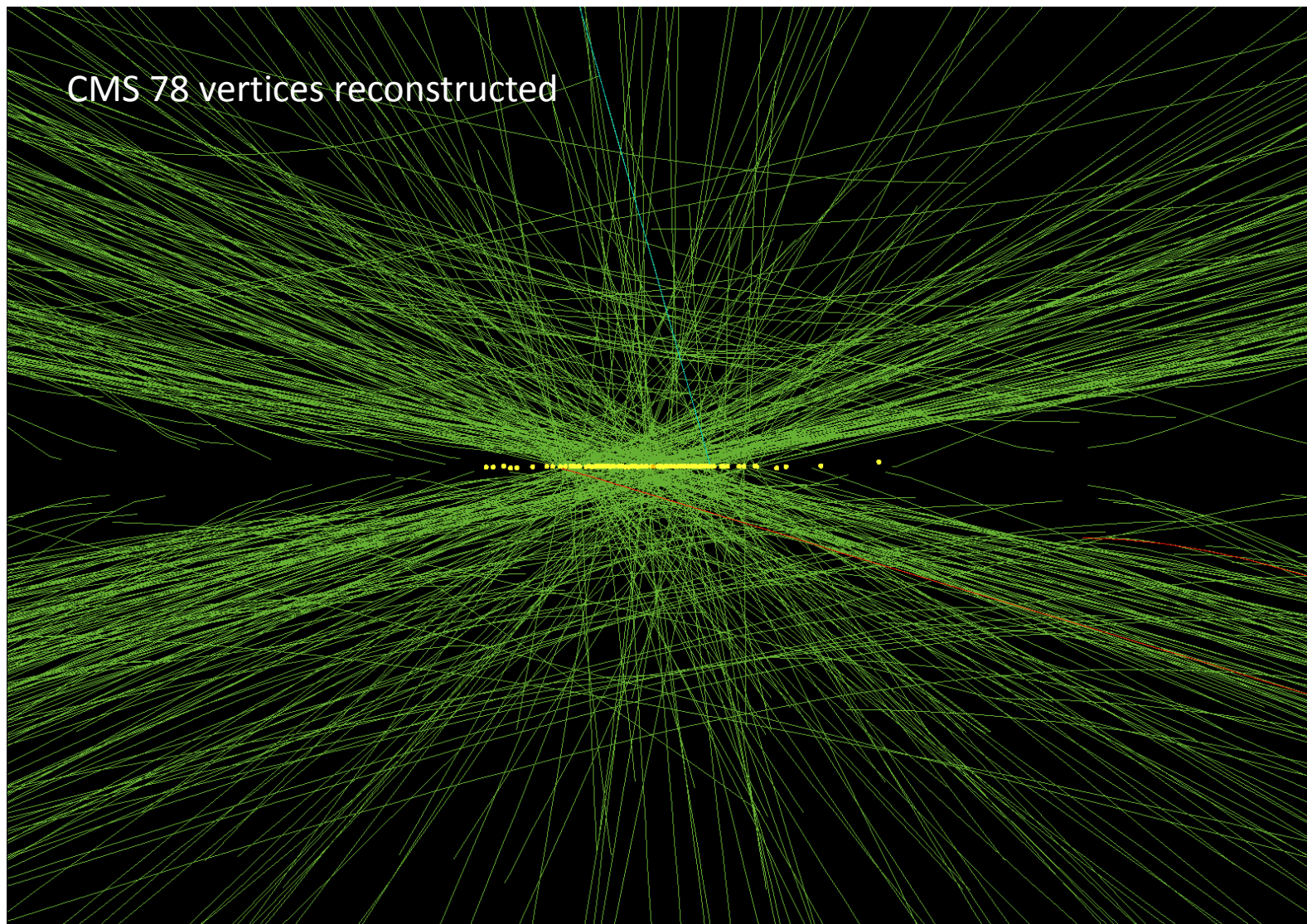
<sup>5</sup>Universita' Piemonte Orientale, Torino, Italy



PSD11: The 11th International Conference on Position Sensitive Detectors  
Milton Keynes 3-8 Sep 2017

Time can be considered a 4<sup>th</sup> dimension coordinate in particle tracking in High Luminosity HEP experiments

Silicon Detectors provide excellent spatial resolution ( **$\sim 10\mu\text{m}$** ), aim is to determine the timing of the passage of the particle with resolution  **$\sim 10\text{ps}$**  (current best performance in NA62, 300x300 $\mu\text{m}$  pixel Gigatracker with **150ps**)




1. Improve reconstruction by adding time information to each track point
2. Determine the correct vertex track assignment

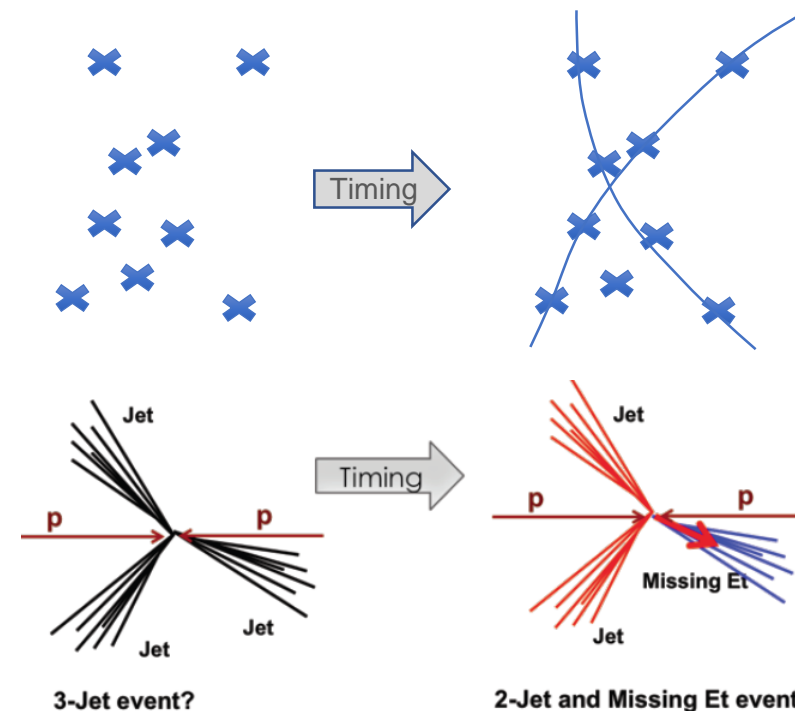
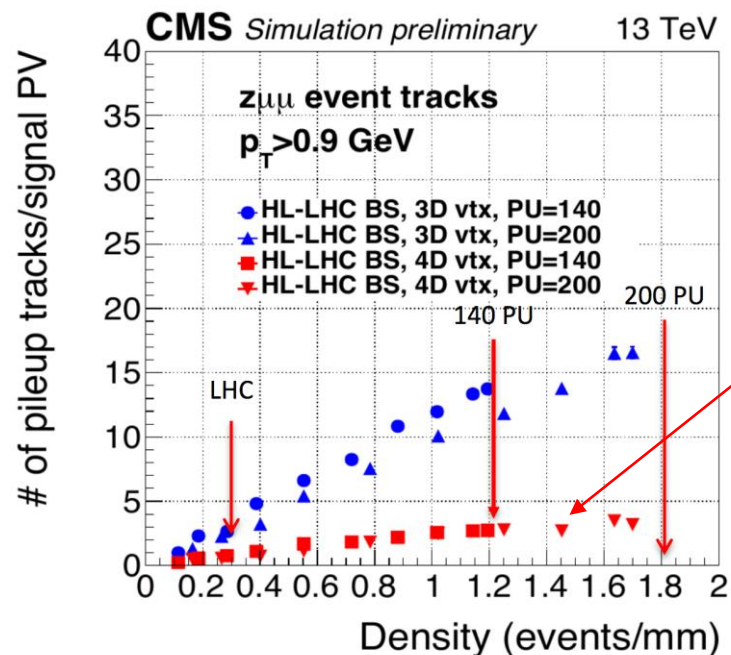
Correct **event reconstruction**

Correct **trigger assignment**

## IN HL-LHC

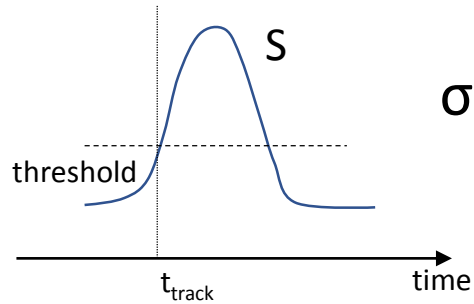
- 150-200 vertices / beam crossing
- $\langle \Delta z_{\text{vertices}} \rangle = 500 \mu\text{m}$
- $\langle t_{\text{vertex}} \rangle_{\text{RMS}} = \sim 200 \text{ps}$
- a vertex separation resolution of  $250\text{-}300 \mu\text{m} \rightarrow 10\text{-}15\%$  overlapping 2 events

 Event loss = Luminosity loss



4D = add 30ps timing information

$\sim \times 5$  pileup (@ PU=200) reduction in terms of associated tracks



$$\sigma_t^2 = \sigma_{\text{Jitter}}^2 + \sigma_{\text{Time Walk}}^2 + \sigma_{\text{Landau Noise}}^2 + \sigma_{\text{Distortion}}^2 + \sigma_{\text{TDC}}^2$$

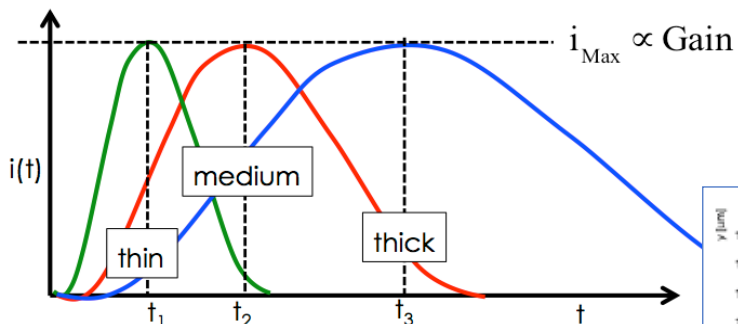
Negligible  
Optimize FE electronics

Negligible  
Optimize RO electronics

$$\sigma_{\text{Jitter}} \approx N / (dV/dt) \approx t_{\text{rise}} / (S/N)$$

→ needs **Gain** to increase S

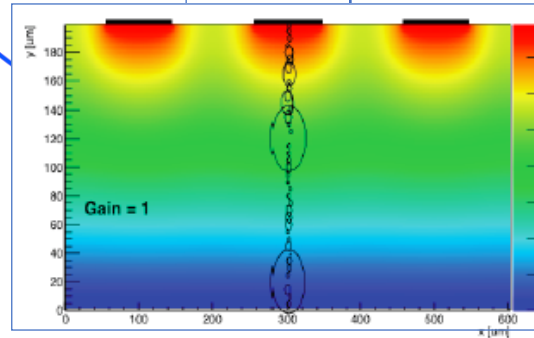
→ needs **thin detector** to decrease  $t_{\text{rise}}$



NB: signal amplitude DOES NOT depend on detector thickness

$$I_{\text{Ramo}} \approx q v_{\text{drift}} E_w$$

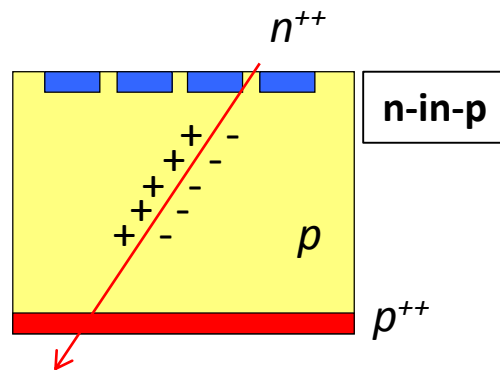
Requires **uniform**  $v_{\text{drift}}$  and  $E_w$



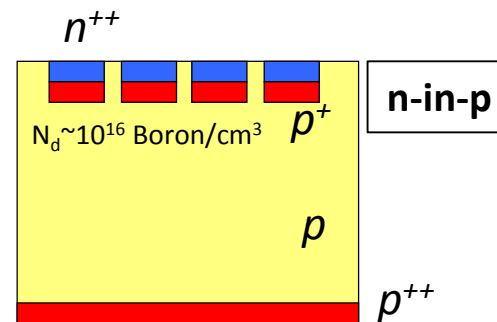
Decreases with detector thickness  
Intrinsic Limit  $\sigma_{\text{Landau Noise}} \approx 20\text{ps}$

use **Low Gain Avalanche Detectors layout** (Gain  $\sim 5$ -20 in  $p^+/n^{++}$  junction with  $E \sim 300 \text{ kV/cm}$ ) and optimize design in order to

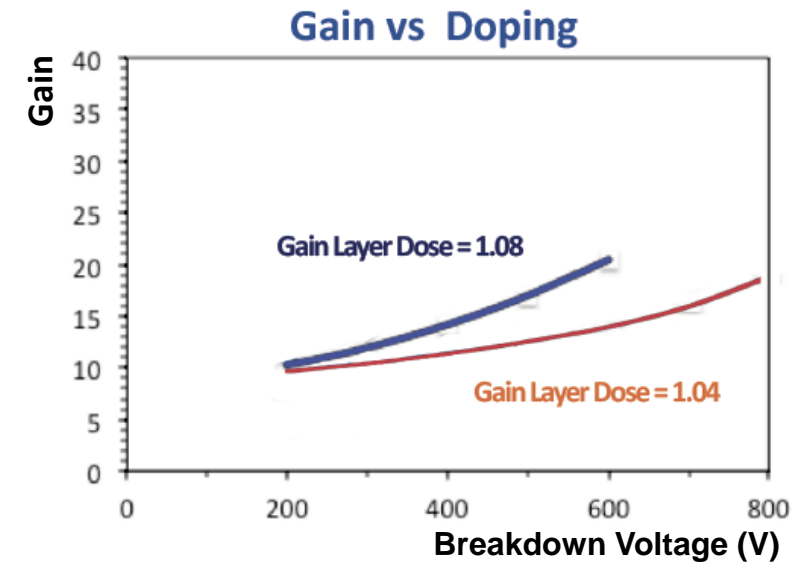
- use high  $E$  to saturate and uniform  $v_{\text{drift}}$
- high resistivity to have uniform  $E$
- use high density segmentation
- low gain  $\rightarrow$  better uniformity
- gain  $\rightarrow$  thin detectors ( $\sim 50 \mu\text{m}$ ) to have low signal  $t_{\text{rise}}$



Traditional Si detectors

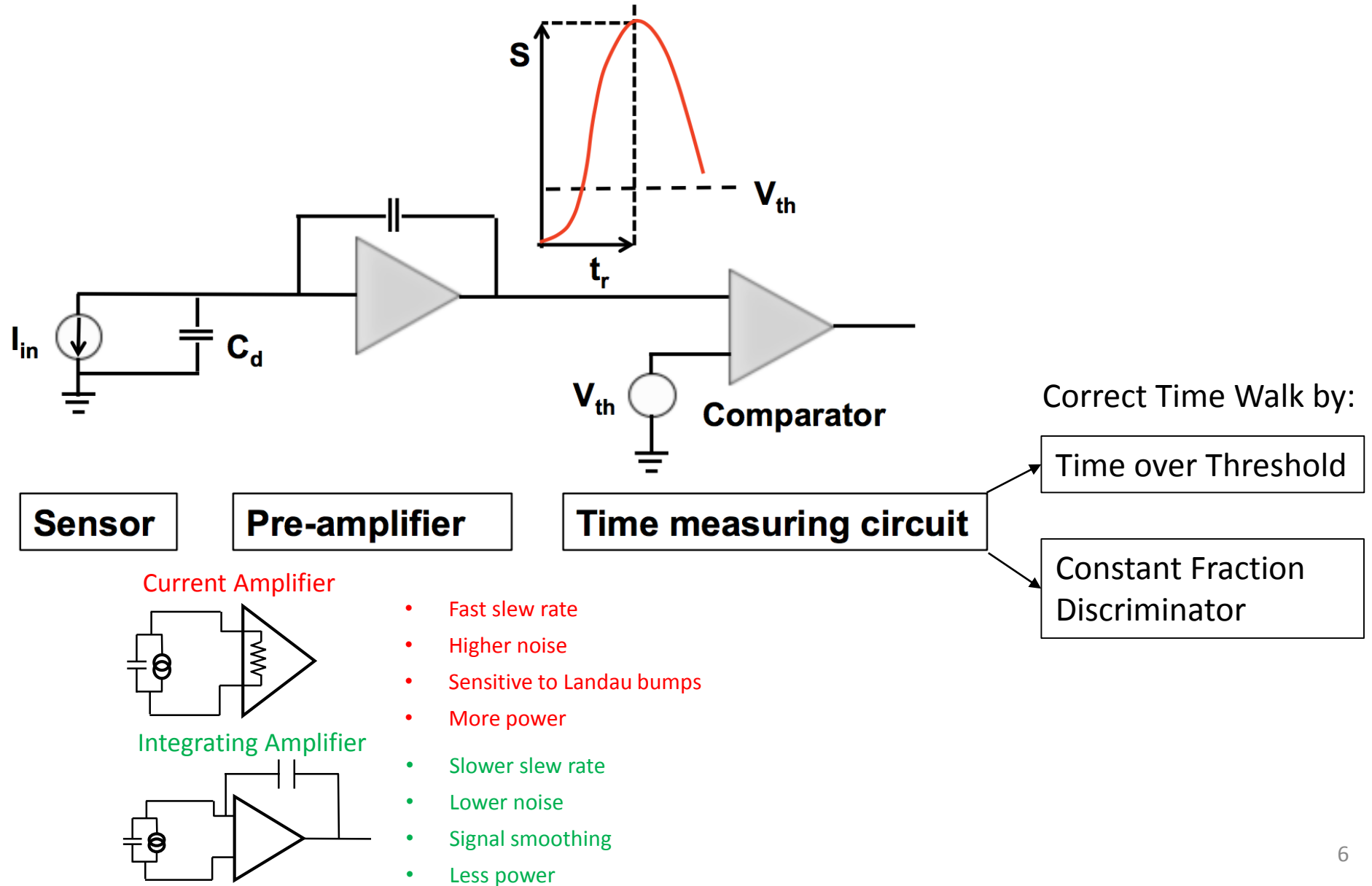


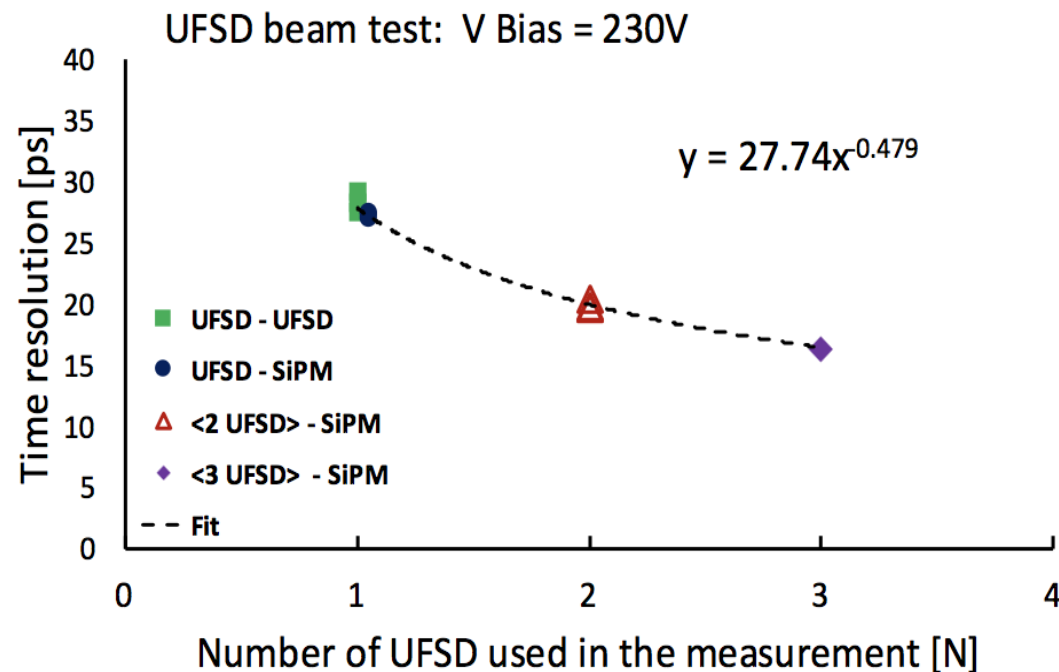
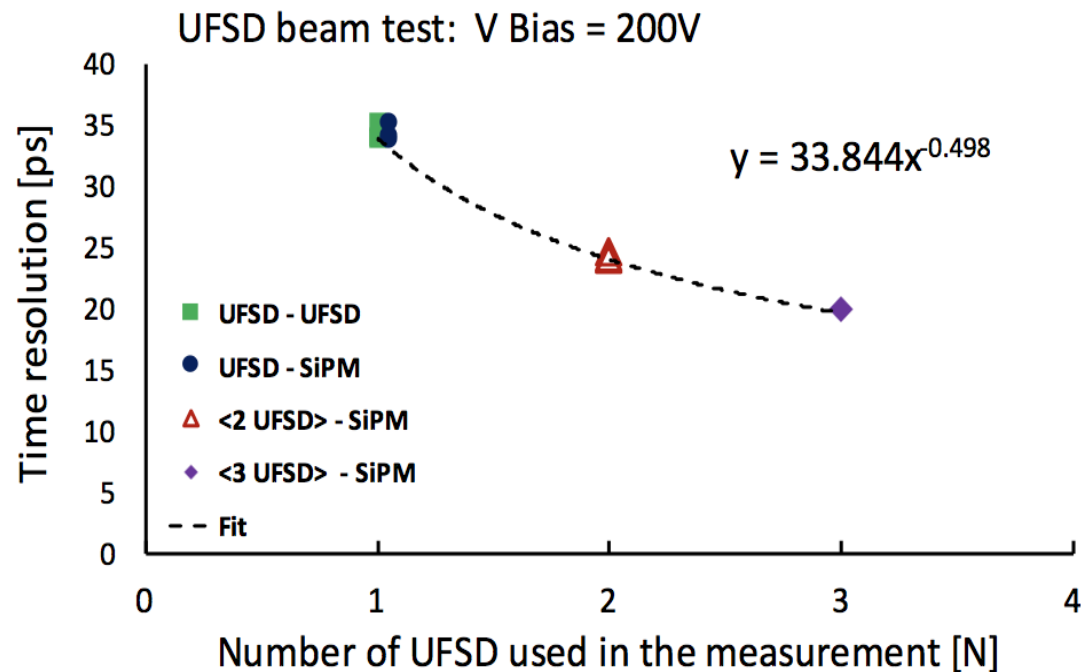
Ultra Fast Si detectors



Gain **very sensitive** to doping concentration (few %)

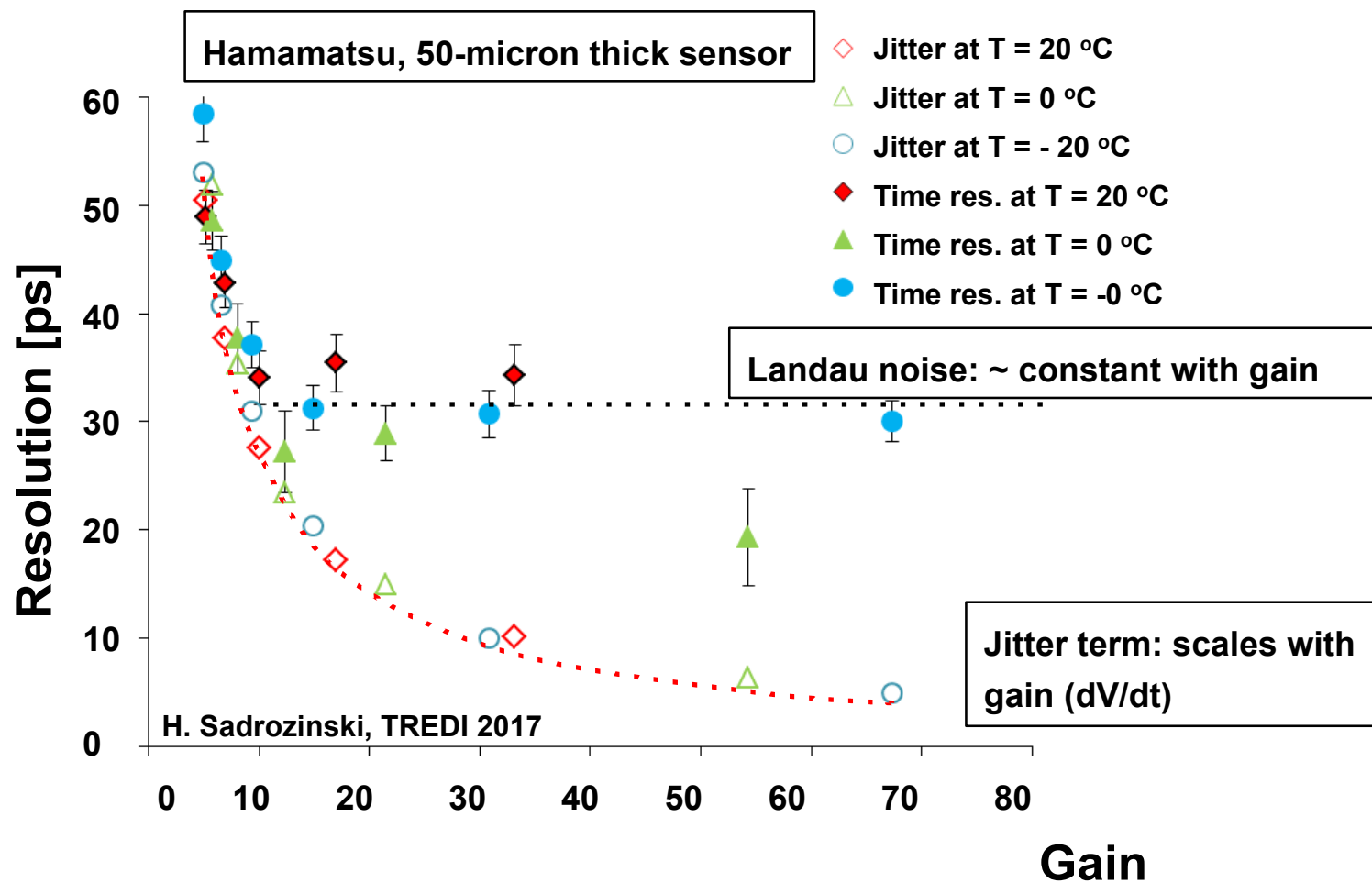






3 **CNM** 45μm thin detectors, 1.7mm<sup>2</sup> single pad + 1 SiPM on quartz for timing crosscheck

The time resolution of a single UFSD is measured to decrease with increased gain M like  $M^{-0.36}$  (from **34ps@200V** to **28ps@230V**)



Consistent with simulation and  
CNM Beam Test Data (previous plot)



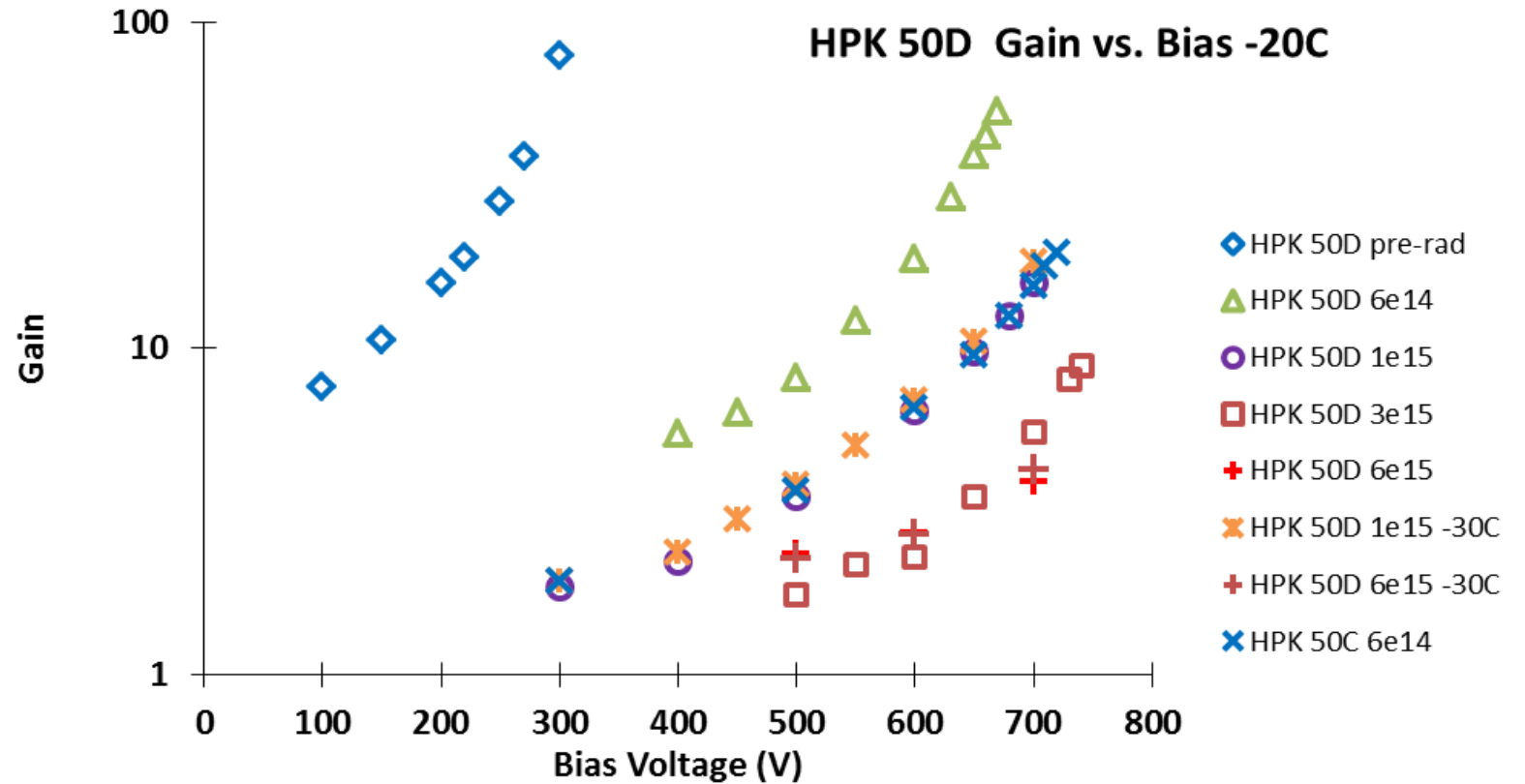
LGAD radiation tolerance studied within the CERN RD50 collaboration

Radiation fluences requested to operate at HL-LHC  $\sim 5 \cdot 10^{15}$  particles/cm<sup>2</sup>, radiation doses of 150Mrad (primarily due to **Non-Ionizing Energy Loss**)

Effects:

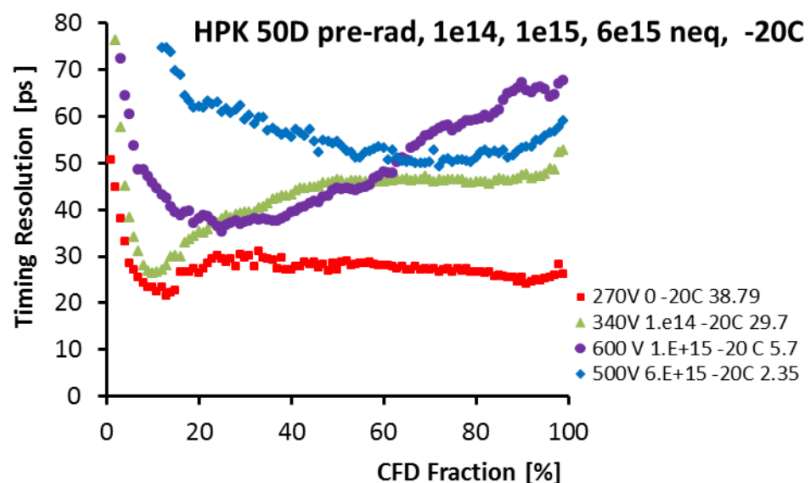
1. Same effects of standard n-p Si detectors: increase of Leakage Current (decrease T), increase of  $V_{BD}$  and  $V_{FD}$ , due to increase of doping concentration. Creation of trapping centers (minimize the effect going to **thin sensors (!)**)
2. In LGAD:
  1. Further increase of leakage current (and power) due to gain layer: **go thin, keep gain low**
  2. Gain loss due to gain layer acceptor removal. Boron atoms are displaced and become interstitial, thus not contributing to the doping profile: **increase  $V_{bias}$ , change acceptor (add Carbon to decrease interstitial phase space, and replace Boron with Gallium)**

Measurements from 50 $\mu$ m thin HPK detectors, fully consistent with simulation expectations: gain decreases with increasing fluences and it is partially recovered by increasing  $V_{\text{Bias}}$

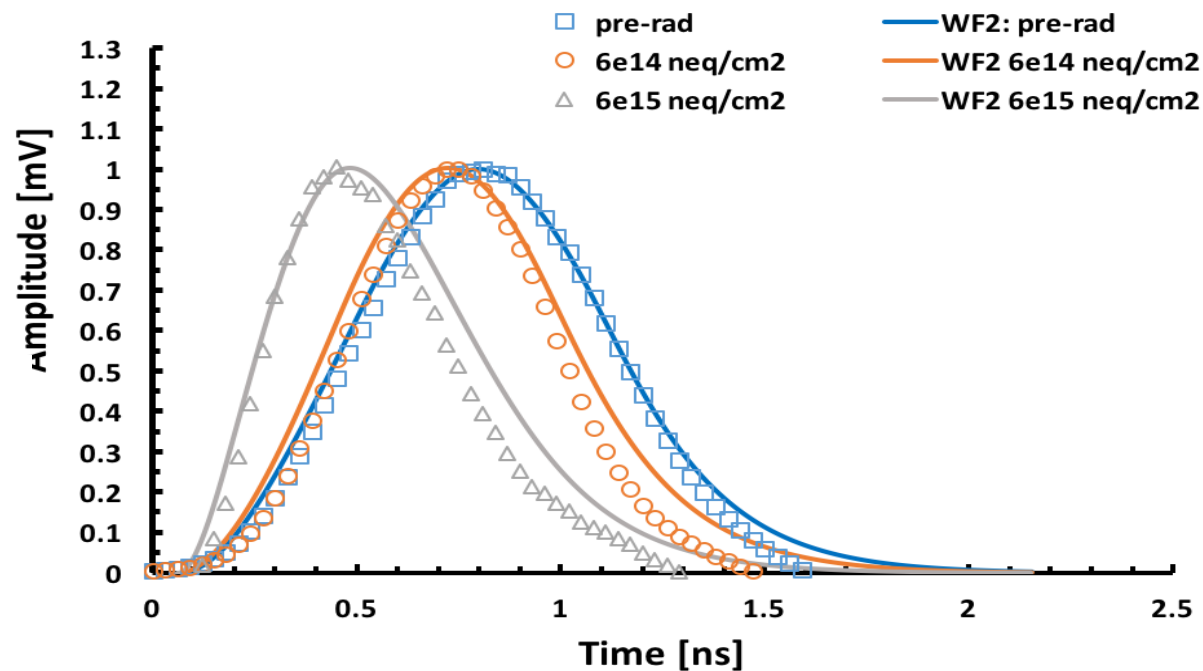


Excellent agreement of signal simulation (WF2) with data.

High fluence increase  $dV/dt$  and shorten the signal. This makes preferable CFD, provided it is tuned vs fluence, over ToT time measurement.

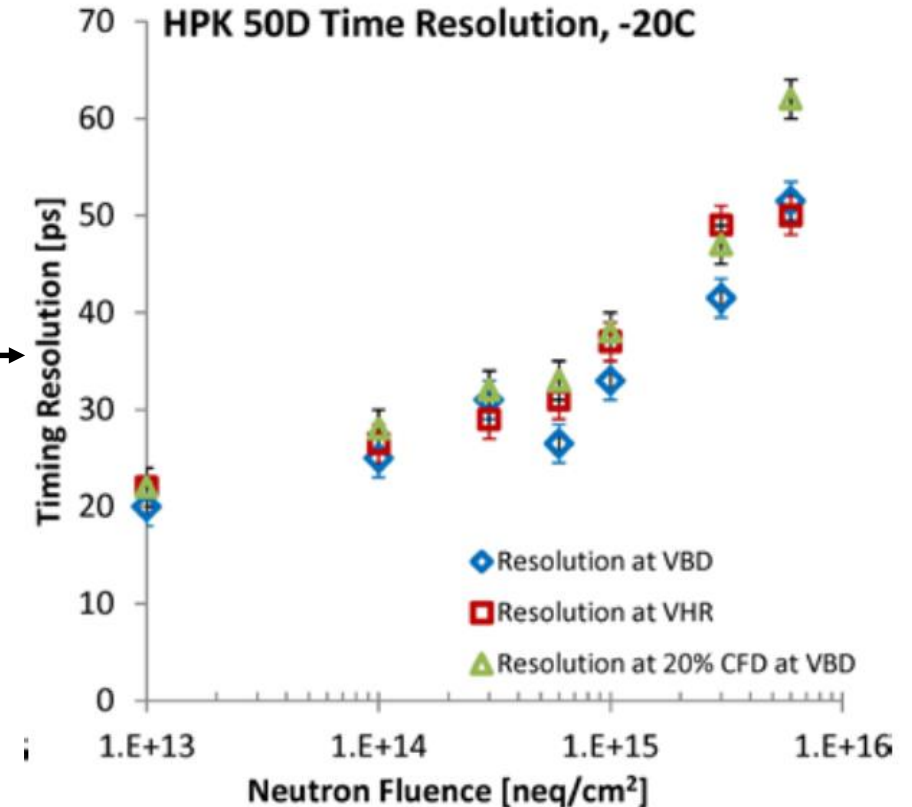


Comparison measured - WF2 pulse of HPK 50D 50-micron thick sensors



Increasing the fluence:

1. Break Down Voltage increases (from 300V at pre-irradiation to 750V at highest tested fluence)
2. Gain at  $V_{BD}$  decreases
3. For a CFD fraction optimized for each fluence and bias, the time resolution increases from 20 ps pre-irradiation to 40 ps at  $1 \cdot 10^{15}$  n/cm<sup>2</sup> up to 50 ps at  $6 \cdot 10^{15}$  n/cm<sup>2</sup> →
4. Even if the gain at large fluences decreases, the increase of the rise time in the pulse height still compensates and guarantees good time resolution
5. Reducing the temperature from -20C to -30C improves the timing resolution by 10% at large fluences where the gain is reduced to below 3.
6. The “headroom” between the breakdown voltage and an operating condition at lower bias causes a reduced timing resolution of a few ps.

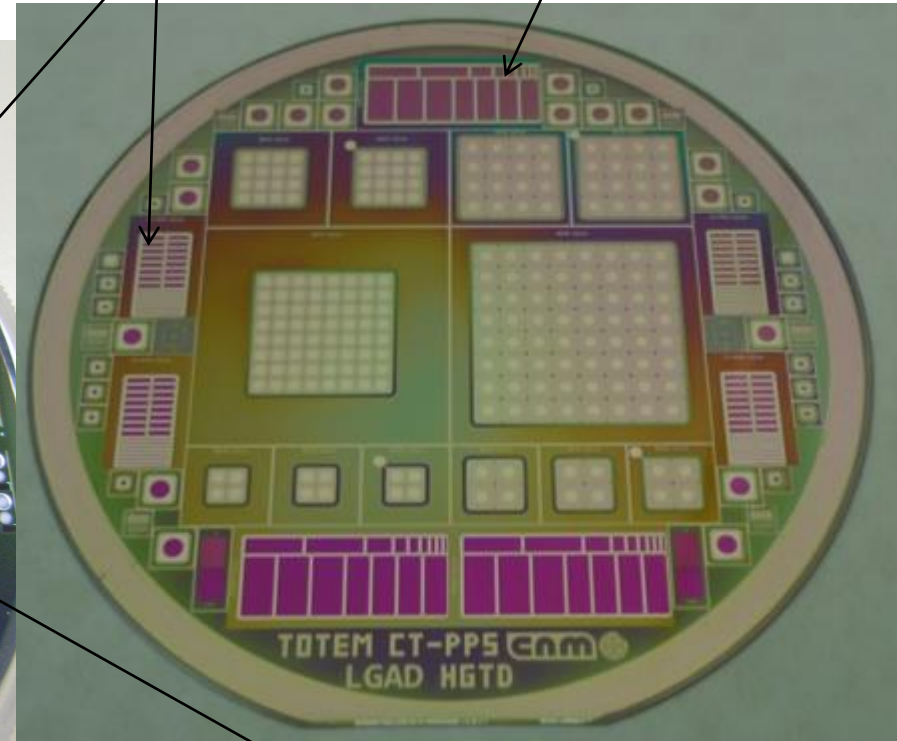
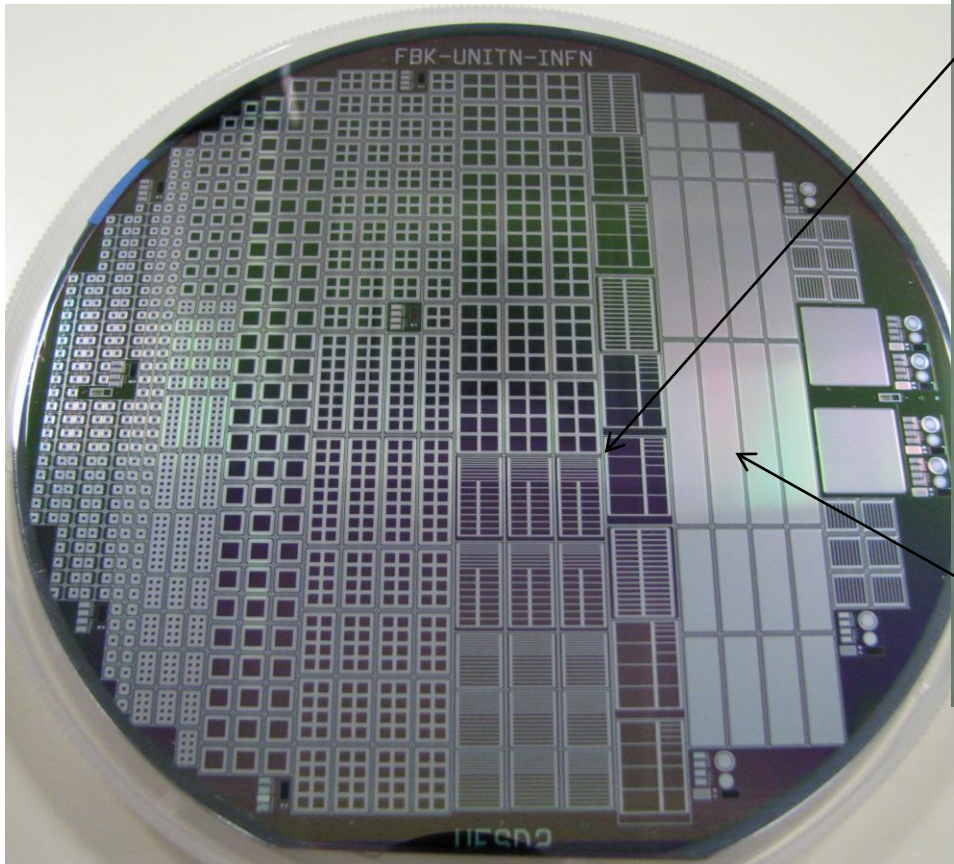


FBK 50-micron production (II FBK Run)  
 Very successful, good gain and overall behavior  
 Gain layer: **Boron, Gallium, Boron+Carbon, Gallium+Carbon**

CNM 75-micron  
 CNM 50-micron production

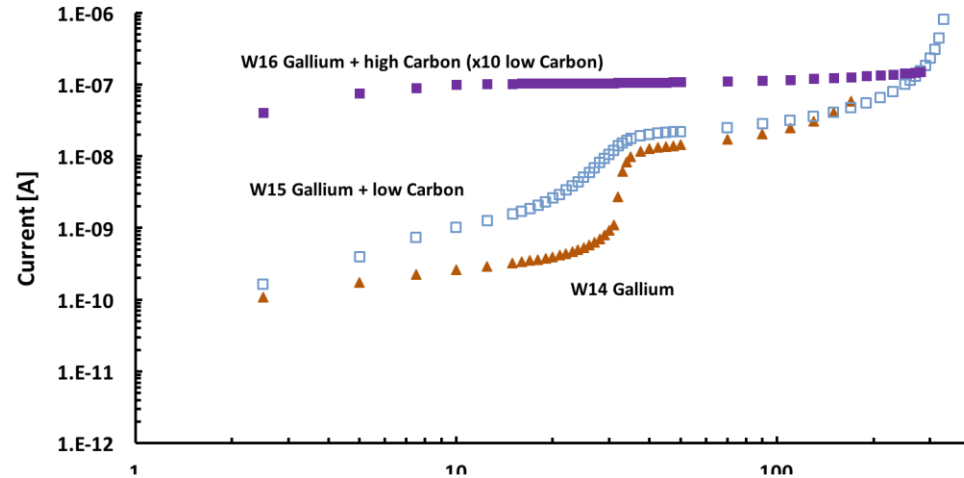
x4 CT-PPS

x3 TOTEM

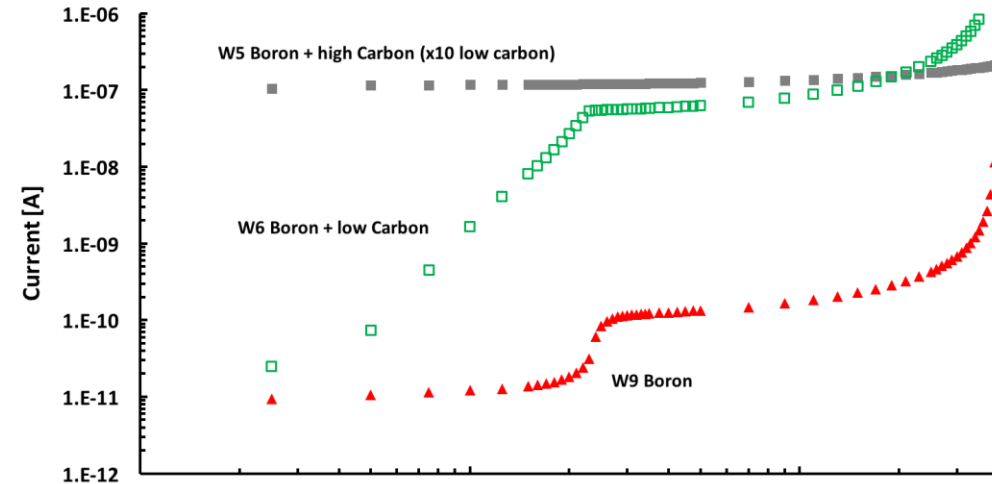


Medical Physics Timing Det.

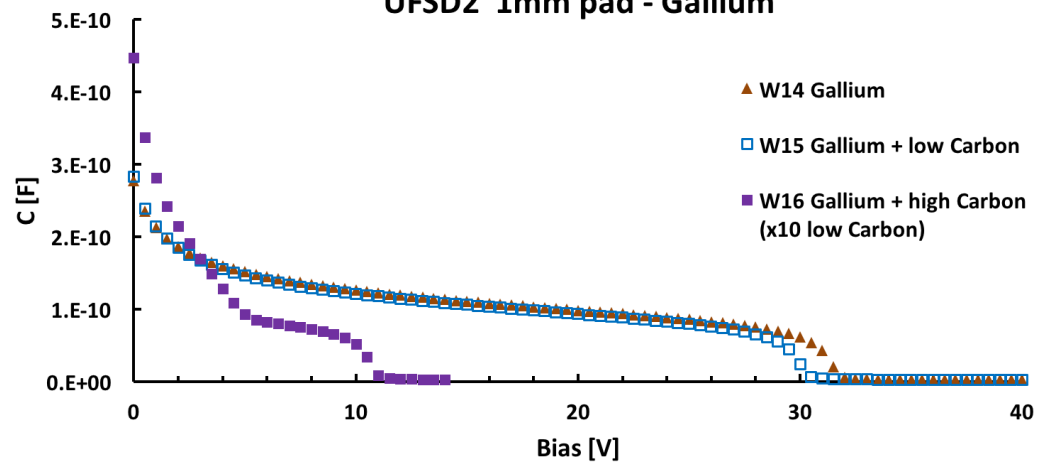
UFSD2 1mm pad - Gallium



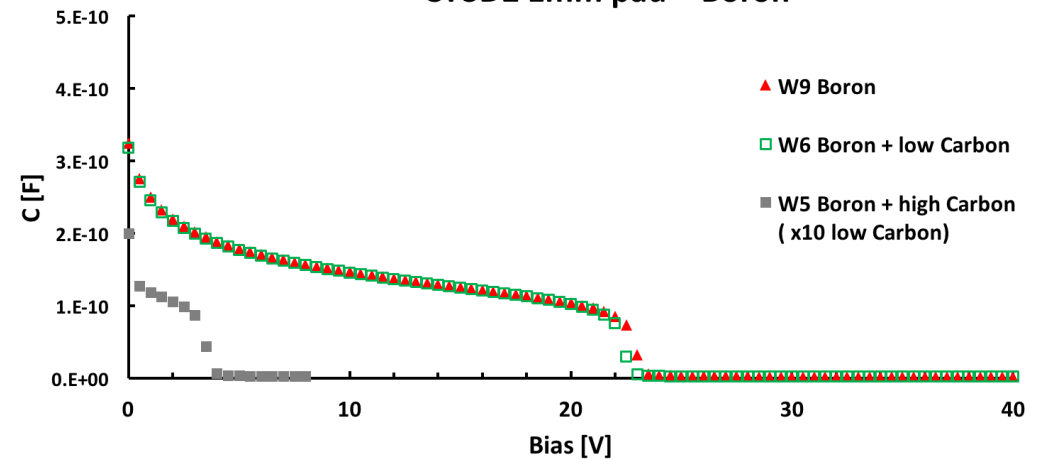
UFSD2 1mm pad - Boron



UFSD2 1mm pad - Gallium



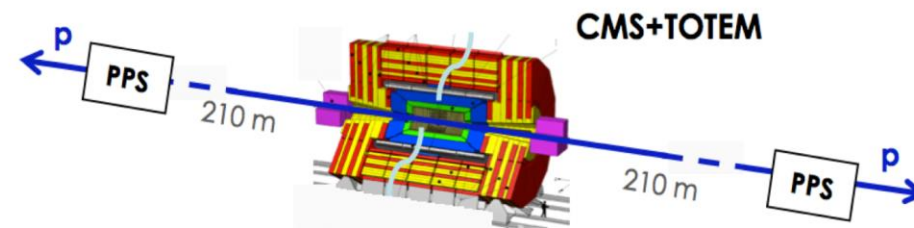
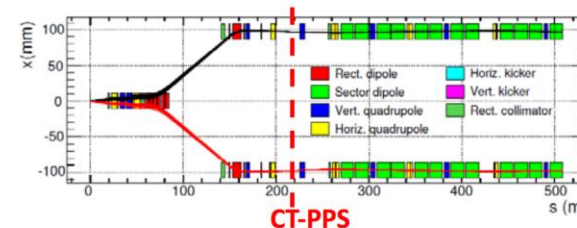
UFSD2 1mm pad - Boron





## CT-PPS Project

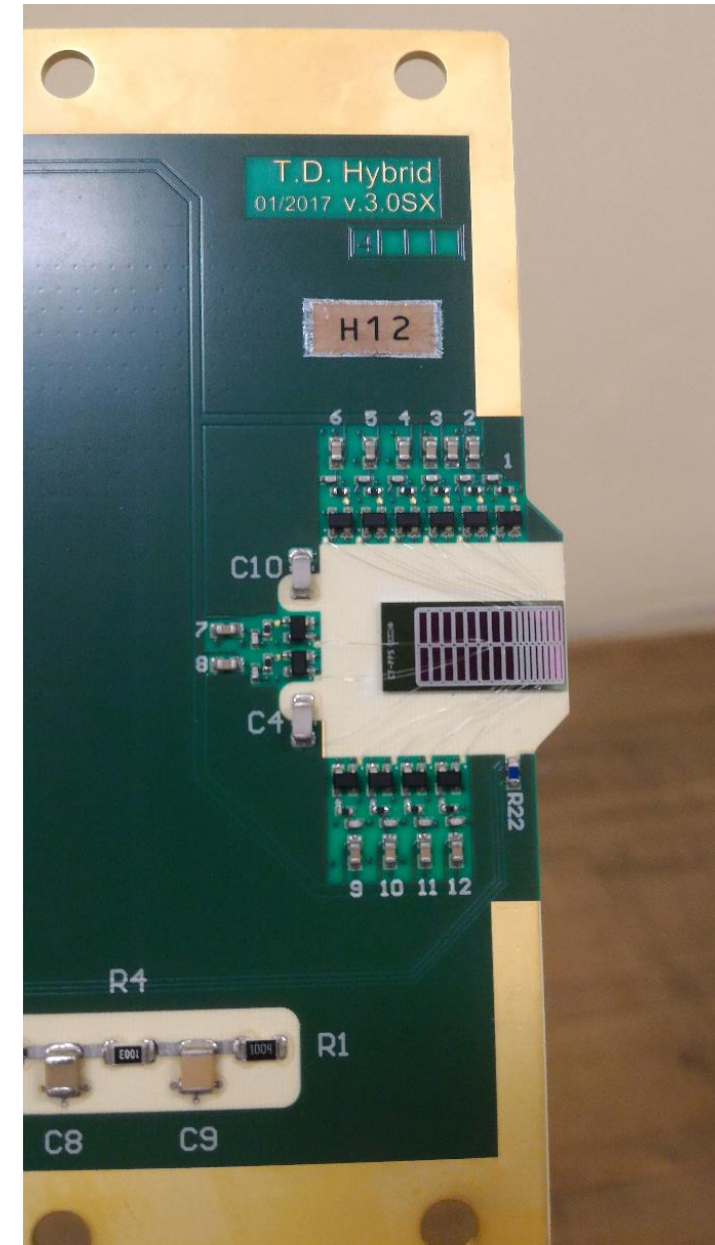
- The CMS TOTEM Precision Proton Spectrometer (CT-PPS) aims at measuring the surviving scattered protons on both sides of CMS in standard LHC running conditions, using LHC magnets to measure the proton momentum
- Tracking and timing detectors at  $\sim 220$  m from CMS inside Roman Pots to be able to move as close as possible to the circulating beams
  - ▷ Tracking to measure proton momentum
  - ▷ Timing to disentangle pile-up
- Project TDR approved in Dec. 2014 by LHCC and CERN Research Board
- CT-PPS already took data in 2016 with an 'accelerated program' configuration (see M. Murray's talk for results)
  - ▷ Si strip & Diamond detectors from TOTEM experiment used
- CT-PPS started data taking with the baseline detector configuration in May 2017 and detector commissioning is ongoing
  - ▷ 3D Silicon Pixels & Strips for tracking
  - ▷ Diamonds + UFSD for timing



1 UFSD Plane installed (first prototype on HEP experiment!)

- 8  $0,5 \times 6 \text{ mm}^2$  and 4  $1 \times 3 \text{ mm}^2$  pads
- Expected time resolution 35ps/plane
- FE electronics on TOTEM custom hybrid
- RO with NINO chip and HPTDC
- Timing signal to be compared with a parallel scCVD Diamond detector

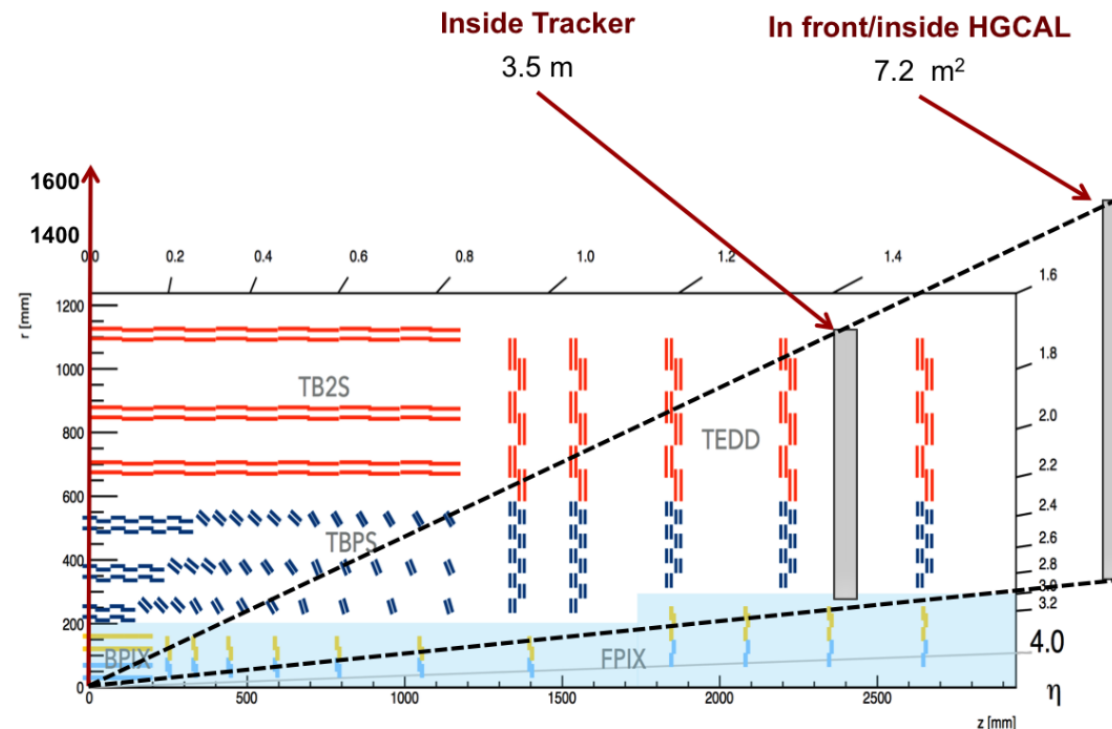
Installation completed in April 2017 and system currently taking data



ATLAS and CMS are discussing the possibility to equip the experiments with a large area Timing Layer made of UFSD.

In CMS would cover the region  $1.45 < \eta < 3$

- keep occupancy  $< 1\%$
- low pad surface area (low leakage current to allow increased  $V_{Bias}$ , typically  $< 3\text{mm}^2$ )
- Low Gain to keep Low noise (Gain  $< 20$ )
- minimize dead area
- sustain fluxes up to  $\sim 10^{15}$  particles/cm<sup>2</sup>
- total detector area  $\sim 10\text{m}^2$



- Good results on timing capabilities (**~30ps** from beam test)
- Good results after NIEL at  **$6 \cdot 10^{15}$  neq/cm<sup>2</sup>**, levels to be considered in HL-LHC. New implants (**Ga, C**) currently under test (last FBK run)
- Good agreement with simulations (**WF2** and **TCAD**)
- Technological interest, many manufacturers (**CNM** (Spain), **FBK** (Italy), **HPK** (Japan), **Micron Semiconductor** (UK))

Thank you for your attention !

This work was supported by the United States Department of Energy, grant DE-FG02-04ER41286. Part of this work has been financed by the European Union's Horizon 2020 Research and Innovation funding program, under Grant Agreement no. 654168 (AIDA-2020) and Grant Agreement no. 669529 (ERC UFSD669529), and by the Italian Ministero degli Affari Esteri and INFN Gruppo V.

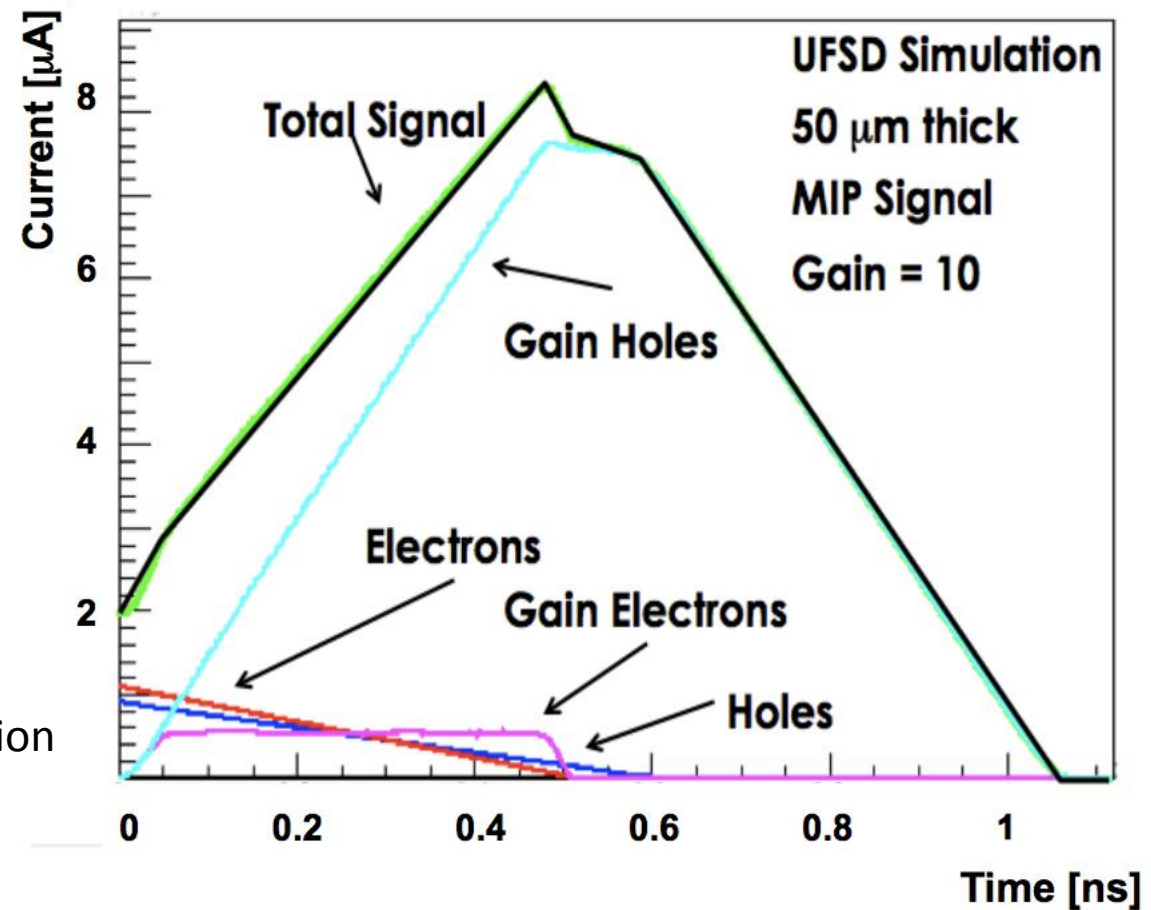




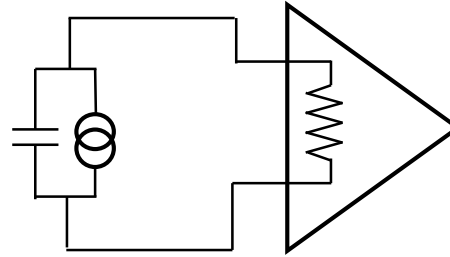
Signal rise-time is given by electrons drift time

Charge formation and multiplication takes a considerable fraction of time.  
Gain Holes dominate the signal, whilst Gain Electrons current contribution is negligible.

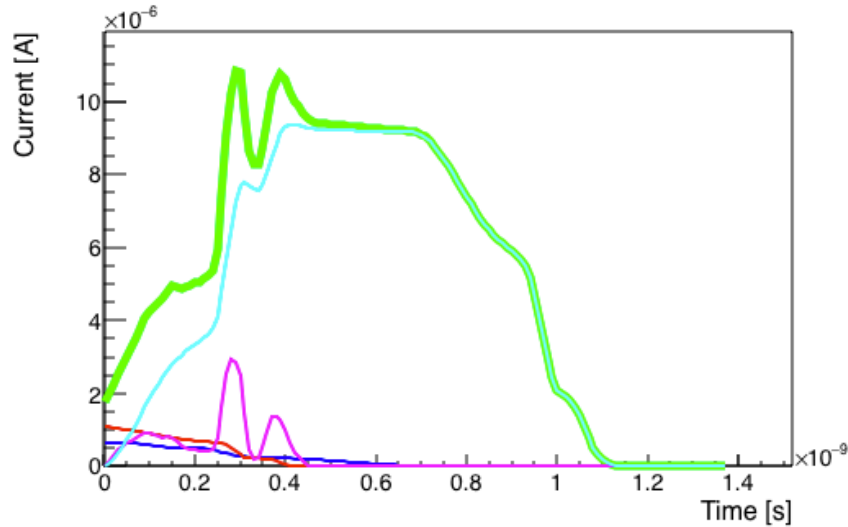
Weightfield2 Simulation



## Current Amplifier

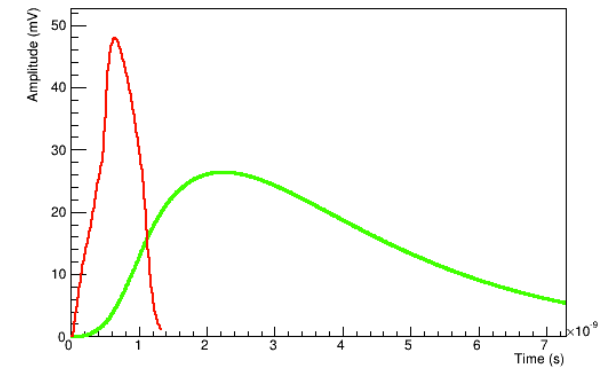


- Fast slew rate
- Higher noise
- Sensitive to Landau bumps
- More power

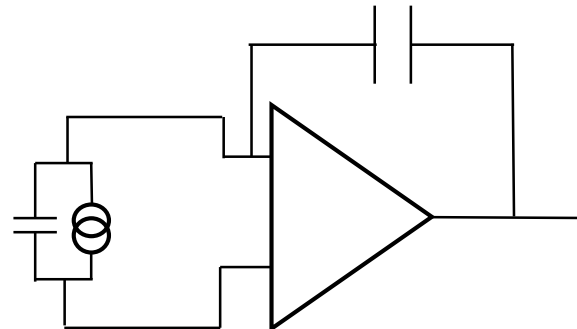


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CSA (green) and Current Amplifier (red)



## Integrating Amplifier



- Slower slew rate
- Lower noise
- Signal smoothing
- Less power

As expected, the jitter contribution follows the inverse of the signal derivative: at the start and at the end of the pulse the contribution decreases, as the pulse shape is less steep. The effect of gain is rather predictable: higher gains yield to lower jitter. The Landau noise term, on the other hand, is rather insensitive to the gain value, but shows a clear dependence upon the CFD settings: it is minimized using the minimum possible threshold.

